TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC595AP,TC74HC595AF,TC74HC595AFN

8-Bit Shift Register/Latch (3-state)

The TC74HC595A is a high speed 8-BIT SHIFT REGISTER/LATCH fabricated with silicon gate C2MOS technology.

It achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC595A contains an 8-bit static shift register which feeds an 8-bit storage register.

Shift operation is accomplished on the positive going transition of the SCK input. The output register is loaded with the contents of the shift register on the positive going transition of the RCK input. Since RCK and SCK signal are independent, parallel outputs can be held stable during the shift operation.

And, since the parallel outputs are 3-state, it can be directly connected to 8-bit bus. This register can be used in serial-to-parallel conversion, data receivers, etc.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

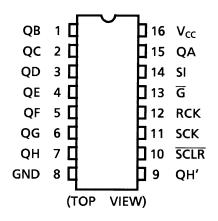
Features

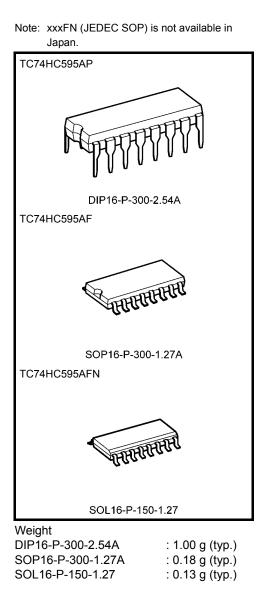
- High speed: $f_{max} = 55 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \pmod{at Ta} = 25^{\circ}C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Output drive capability: 15 LSTTL loads for QA to QH 10 LSTTL loads for QH'
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 6 \text{ mA} (\text{min})$ For QA to QH

 $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$ For QH'

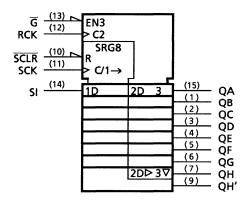
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 6 V
- Pin and function compatible with 74LS595

Pin Assignment





IEC Logic Symbol



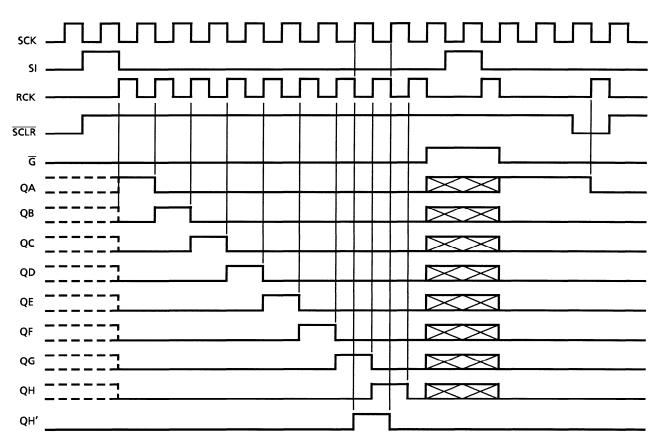
Truth Table

	Inputs				Function			
SI	SCK	SCLR	RCK	IJ	T difetion			
Х	Х	Х	Х	Н	QA thru QH outputs disable			
Х	Х	Х	Х	L	QA thru QH outputs enable			
Х	Х	L	Х	Х	Shift register is cleared.			
L		Н	х	х	First stage of S.R. becomes "L". Other stages store the data of previous stage, respectively.			
н		Н	х	х	First stage of S.R. becomes "H". Other stages store the data of previous stage, respectively.			
Х	\rightarrow	Н	Х	Х	State of S.R. is not changed.			
Х	Х	Х		Х	S.R. data is stored into storage register.			
Х	Х	Х		Х	Storage register stage is not changed.			

X: Don't care

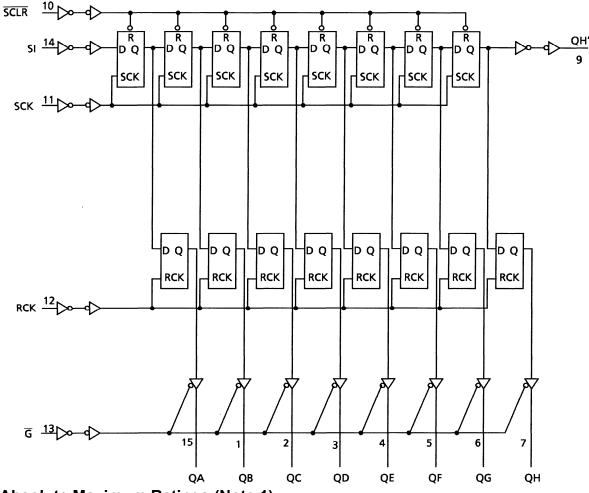
TOSHIBA

Timing Chart



<u>TOSHIBA</u>

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	IIК	±20	mA
Output diode current	I _{OK}	±20	mA
DC output current (QH')		±25	m۸
(QA to QH)	IOUT	±35	mA
DC V _{CC} /ground current	ICC	±75	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2 to 6	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 ($V_{CC} = 4.5 \text{ V}$)	ns
		0 to 400 ($V_{CC} = 6.0 \text{ V}$)	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C		Ta = -40 to 85°C		Unit		
					V _{CC} (V)	Min	Тур.	Max	Min	Max	
					2.0	1.50	_	_	1.50	_	
High-level input voltage	VIH	_		_	4.5	3.15	_	_	3.15	_	V
· · · · · · · · · · · · · · · · · · ·					6.0	4.20	—	—	4.20		
					2.0			0.50		0.50	
Low-level input voltage	V _{IL}			_	4.5	_	—	1.35		1.35	V
				6.0	_	—	1.80	_	1.80		
					2.0	1.9	2.0	_	1.9	_	v
		VIN = V	۱ /iн or Vii	I _{OH} = -20 μA	4.5	4.4	4.5	—	4.4		
					6.0	5.9	6.0	—	5.9	—	
High-level output voltage	V _{OH}		QH'	I _{OH} = -4 mA	4.5	4.18	4.31	_	4.13	_	v
				$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	—	5.63	—	
			QA to QH	I _{OH} = -6 mA	4.5	4.18	4.31	_	4.13		
				I _{OH} = -7.8 mA	6.0	5.68	5.80	—	5.63	—	
				I _{OL} = 20 μA	2.0	_	0.0	0.1	_	0.1	
		VIN = \	N /IH or VIL		4.5	—	0.0	0.1	_	0.1	V
					6.0		0.0	0.1	—	0.1	
Low-level output voltage	V _{OL}		QH'	$I_{OL} = 4 \text{ mA}$	4.5	—	0.17	0.26	—	0.33	
J. J			Qn	$I_{OL} = 5.2 \text{ mA}$	6.0		0.18	0.26	—	0.33	v
			QA to	$I_{OL} = 6 \text{ mA}$	4.5		0.17	0.26	_	0.33	v
			QH	I _{OL} = 7.8 mA	6.0		0.18	0.26		0.33	
3-state output off-state current	I _{OZ}		N = V _{IH} or		6.0	_	_	±0.5	_	±5.0	μΑ
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND			6.0		_	±0.1	_	±1.0	μA
Quiescent supply current	ICC	VIN	1 = A ^{CC} oi	r GND	6.0		_	4.0	_	40.0	μΑ

Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Test Condition			Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	the give		2.0		75	95	
(SCK, RCK)	tw (H)	—	4.5	—	15	19	ns
	t₩ (L)		6.0	_	13	16	
Minimum pulse width			2.0	—	75	95	
(SCLR)	t _{W (L)}	—	4.5	—	15	19	ns
(SOLK)			6.0	_	13	16	
Minimum set-up time			2.0	—	50	65	
(SI-SCK)	ts	—	4.5	—	10	13	ns
			6.0		9	11	
Minimum set-up time	t _s		2.0	—	75	95	
(SCK-RCK)		—	4.5	—	15	19	ns
			6.0		13	16	
Minimum set-up time			2.0	—	100	125	
(SCLR -RCK)	ts	—	4.5	—	20	25	ns
(BOLK-KOK)			6.0	_	17	21	
			2.0	—	0	0	
Minimum hold time	t _h	—	4.5	—	0	0	ns
			6.0	_	0	0	
Minimum removal time			2.0	_	50	65	
(SCLR)	t _{rem}	—	4.5	—	10	13	ns
			6.0	_	9	11	
			2.0	_	6	5	
Clock frequency	f	—	4.5	—	30	25	MHz
			6.0	—	35	28	

AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time (QH')	t _{TLH} t _{THL}	_	_	4	8	ns
Propagation delay time (SCK-QH')	^t pLH t _{pHL}	—	_	12	21	ns
Propagation delay time (SCLR -QH')	t _{pHL}	—	_	15	30	ns
Maximum clock frequency	f _{max}	—	35	77	_	MHz

AC Characteristics (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Co	Test Condition		-	Ta = 25°C)	Ta = -40 to 85°C		Unit
	0,11201		CL (pF)	V _{CC} (V)	Min	Тур.	Max	Min	Max	•••••
	4			2.0	_	25	60		75	
Output transition time	t _{TLH}		50	4.5	_	7	12	—	15	ns
(Q _n)	t _{THL}			6.0	_	6	10		13	
Output transition time	4			2.0		30	75		95	
Output transition time	t _{TLH}		50	4.5	_	8	15	—	19	ns
(QH')	t _{THL}			6.0	_	7	13	_	16	
Propagation delay	4			2.0		45	125		155	
time	t _{pLH}	—	50	4.5	_	15	25	_	31	ns
(SCK-QH')	t _{pHL}			6.0	_	13	21		26	
Propagation delay				2.0		60	175		220	
time	t _{pHL}	—	50	4.5	_	18	35	_	44	ns
(SCLR-QH')				6.0	_	15	30		37	
				2.0		60	150		190	
	t _{pLH} t _{pHL}	_	50	4.5	_	20	30		38	- ns
Propagation delay time				6.0	_	17	26		32	
(RCK-Q _n)			150	2.0		75	190		240	
(4.5	_	25	38		48	
				6.0	_	22	32		41	
				2.0		45	135	_	170	
			50	4.5		15	27		34	
Output an able time.	t _{pZL}			6.0	_	13	23		29	
Output enable time	t _{pZH}	$R_L = 1 \ k\Omega$		2.0	_	60	175	_	220	- ns
			150	4.5	_	20	35		44	
				6.0		17	30		37	
	4			2.0		30	150		190	
Output disable time	t _{pLZ}	$R_L = 1 \ k\Omega$	50	4.5	_	15	30		38	ns
	t _{pHZ}			6.0	—	14	26	—	33	
				2.0	6	17		5		
Maximum clock frequency	f _{max}	—	50	4.5	30	50	_	25	_	MHz
nequency				6.0	35	59	_	28	—	
Input capacitance	C _{IN}	_	-	•	_	5	10		10	pF
Power dissipation capacitance	C _{PD} (Note)	_	_			184				pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

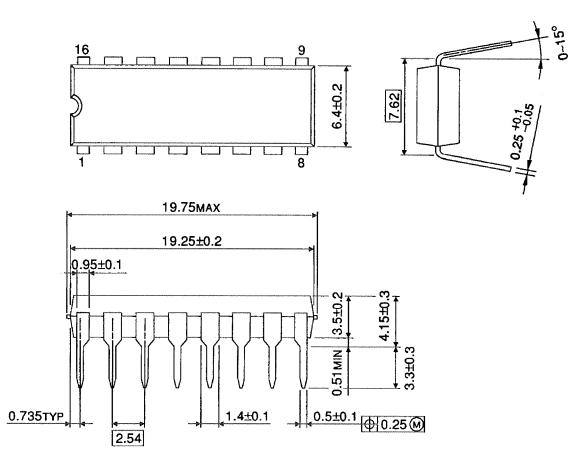
Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

DIP16-P-300-2.54A

Unit : mm



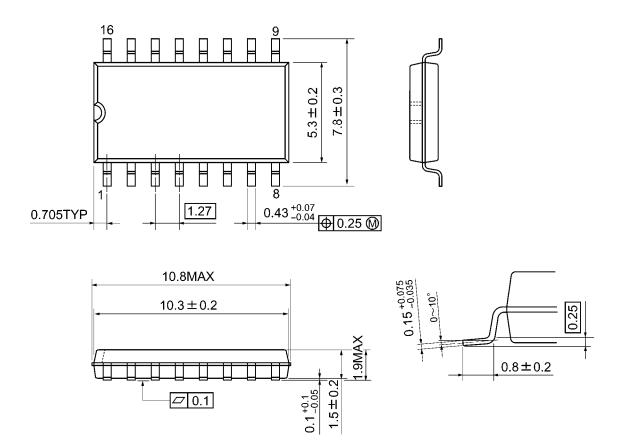
Weight: 1.00 g (typ.)



Package Dimensions

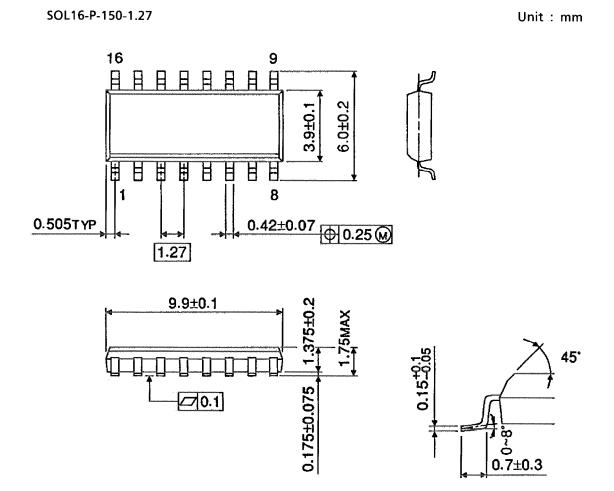
SOP16-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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